

TC74HC4060AP, TC74HC4060AF

14-Stage Binary Counter/Oscillator

The TC74HC4060A is a high speed CMOS 14-STAGE BINARY COUNTER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The oscillator configuration allows designs using either RC or crystal oscillator circuits, or an external clock may be used.

The clear input resets the counter to a low level on all outputs and disables the oscillator.

A high CLR accomplishes this reset function.

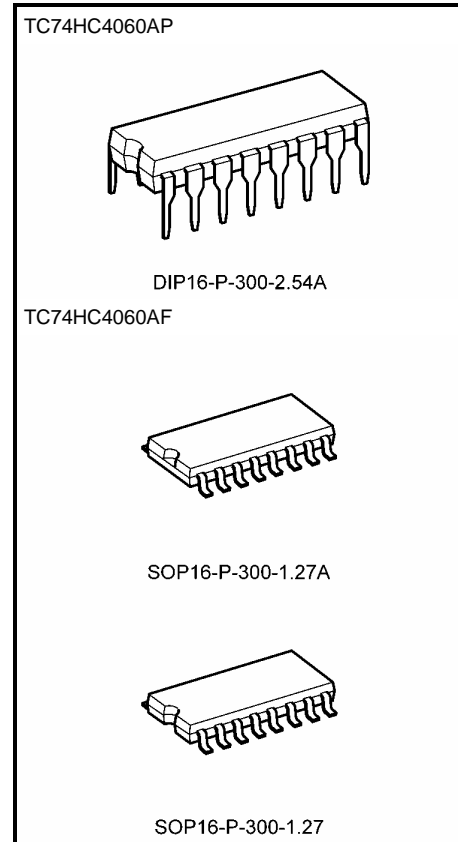
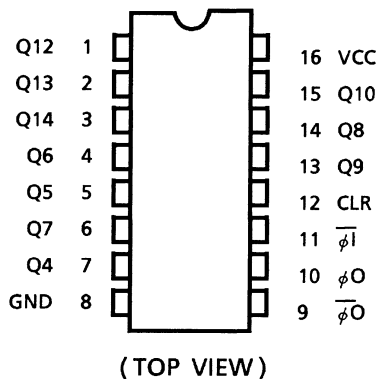
A negative transition on the clock input ($\overline{\phi I}$) increments the counter. Ten levels of divided output are provided; 4 stage thru 10 stage and 12 stage thru 14 stage. At the last stage (Q14), a 1/16384 divided frequency is obtained.

The $\overline{\phi I}$ input and CLR input are equipped with protection circuits against static discharge or transient excess voltage.

Features

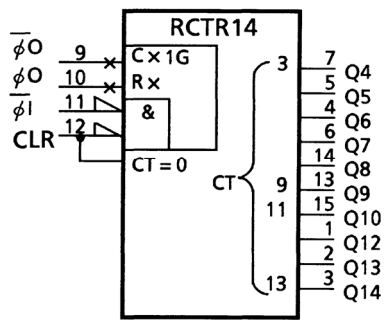
- High speed: $f_{\max} = 58 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu\text{A}$ (max) at $T_a = 25^\circ\text{C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 4 \text{ mA}$ (min)
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC} (\text{opr}) = 2 \text{ to } 6 \text{ V}$
- Oscillator configuration: RC or crystal oscillator
- Pin and function compatible with 4060B

Pin Assignment



Weight	
DIP16-P-300-2.54A	: 1.00 g (typ.)
SOP16-P-300-1.27A	: 0.18 g (typ.)
SOP16-P-300-1.27	: 0.18 g (typ.)

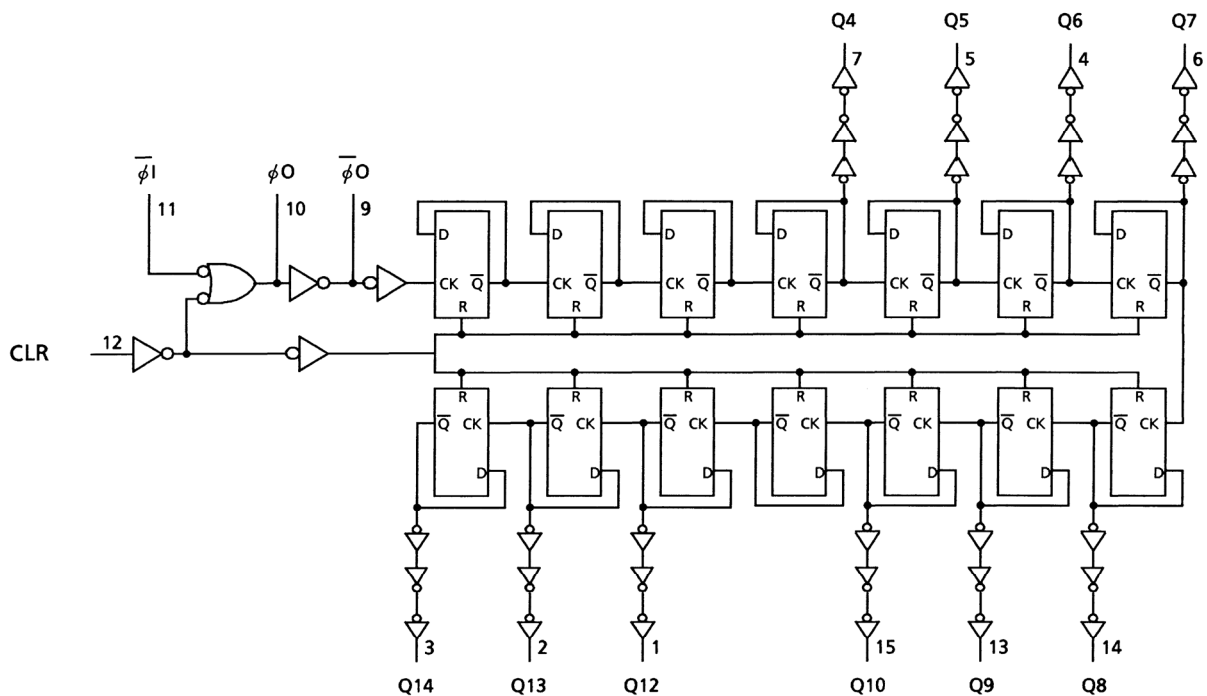
IEC Logic Symbol



Truth Table

Inputs		Function
$\bar{\phi}I$	CLR	
X	H	Counter is reset to zero state. ϕO output goes to high level. $\bar{\phi}O$ output goes to low level.
	L	Count up one step.
	L	No Change

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7	V
DC input voltage	V_{IN}	-0.5 to $V_{CC} + 0.5$	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	± 20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 50	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T_{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of $T_a = -40$ to 65°C . From $T_a = 65$ to 85°C a derating factor of $-10 \text{ mW}/^\circ\text{C}$ shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2 to 6	V
Input voltage	V_{IN}	0 to V_{CC}	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	t_r, t_f	0 to 1000 ($V_{CC} = 2.0 \text{ V}$) 0 to 500 ($V_{CC} = 4.5 \text{ V}$) 0 to 400 ($V_{CC} = 6.0 \text{ V}$)	ns

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics
DC Characteristics

Characteristics	Symbol	Test Condition		V _{CC} (V)	Ta = 25°C			Ta = −40 to 85°C		Unit
					Min	Typ.	Max	Min	Max	
High-level input voltage	V _{IH}	—		2.0 4.5 6.0	1.50 3.15 4.20	— — —	— — —	1.50 3.15 4.20	— — —	V
Low-level input voltage	V _{IL}	—		2.0 4.5 6.0	— — —	— — —	0.50 1.35 1.80	— — —	0.50 1.35 1.80	V
High-level output voltage (Qn)	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = −20 μA	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
			I _{OH} = −4 mA I _{OH} = −5.2 mA	6.0	5.9	6.0	—	5.9	—	
				4.5	4.18	4.31	—	4.13	—	
High-level output voltage (φO, φ̄O)	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = −20 μA	6.0	5.68	5.80	—	5.63	—	V
				2.0	1.8	2.0	—	1.8	—	
				4.5	4.0	4.5	—	4.0	—	
Low-level output voltage (Qn)	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0	—	0.0	0.1	—	0.1	V
				4.5	—	0.0	0.1	—	0.1	
			I _{OL} = 4 mA I _{OL} = 5.2 mA	6.0	—	0.0	0.1	—	0.1	
				4.5	—	0.17	0.26	—	0.33	
Low-level output voltage (φO, φ̄O)	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	6.0	—	0.18	0.26	—	0.33	V
				2.0	—	0.0	0.2	—	0.2	
				4.5	—	0.0	0.5	—	0.5	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0	—	—	4.0	—	40.0	μA

Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = -40 to 85°C	Limit	Unit
			V _{CC} (V)	Typ.			
Minimum pulse width ($\bar{\phi}$)	t_W (L) t_W (H)	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum pulse time (CLR)	t_W (H)	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum removal time	t_{rem}	—	2.0	—	100	125	ns
			4.5	—	20	25	
			6.0	—	17	21	
Clock frequency	f	—	2.0	—	6	5	MHz
			4.5	—	30	24	
			6.0	—	35	28	

AC Characteristics ($C_L = 15 \text{ pF}$, $V_{CC} = 5 \text{ V}$, Ta = 25°C, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Output transition time	t_{TLH}	—	—	4	8	ns
	t_{THL}					
Propagation delay time ($\bar{\phi}$ - Q ₄)	t_{pLH}	—	—	36	53	ns
	t_{pHL}					
Propagation delay time difference (Q _n - Q _{n + 1})	Δt_{pd}	$C_L = 15 \text{ pF}$ (Q _n , Q _{n + 1})	—	6	14	ns
Propagation delay time (CLR)	t_{pHL}	—	—	19	34	ns
Maximum clock frequency	f_{max}	—	33	58	—	MHz

AC Characteristics ($C_L = 50$ pF, input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40$ to 85°C		Unit
				Min	Typ.	Max	Min	Max	
Output transition time	t_{TLH} t_{THL}	—	2.0	—	30	75	—	95	ns
			4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation delay time ($\bar{\phi}_I - Q_4$)	t_{PLH} t_{PHL}	—	2.0	—	170	300	—	375	ns
			4.5	—	41	60	—	75	
			6.0	—	30	51	—	64	
Propagation delay time difference ($Q_n - Q_{n+1}$)	Δt_{pd}	$C_L = 50$ pF (Q_n, Q_{n+1})	2.0	—	32	75	—	95	ns
			4.5	—	7	15	—	19	
			6.0	—	5	13	—	16	
Propagation delay time (CLR)	t_{PHL}	—	2.0	—	85	195	—	245	ns
			4.5	—	23	39	—	49	
			6.0	—	17	33	—	42	
Maximum clock frequency	f_{max}	—	2.0	6	12	—	5	—	MHz
			4.5	30	50	—	24	—	
			6.0	35	65	—	28	—	
Input capacitance	C_{IN}	—	—	—	5	10	—	10	pF
Power dissipation capacitance	C_{PD}	(Note)	—	—	27	—	—	—	pF

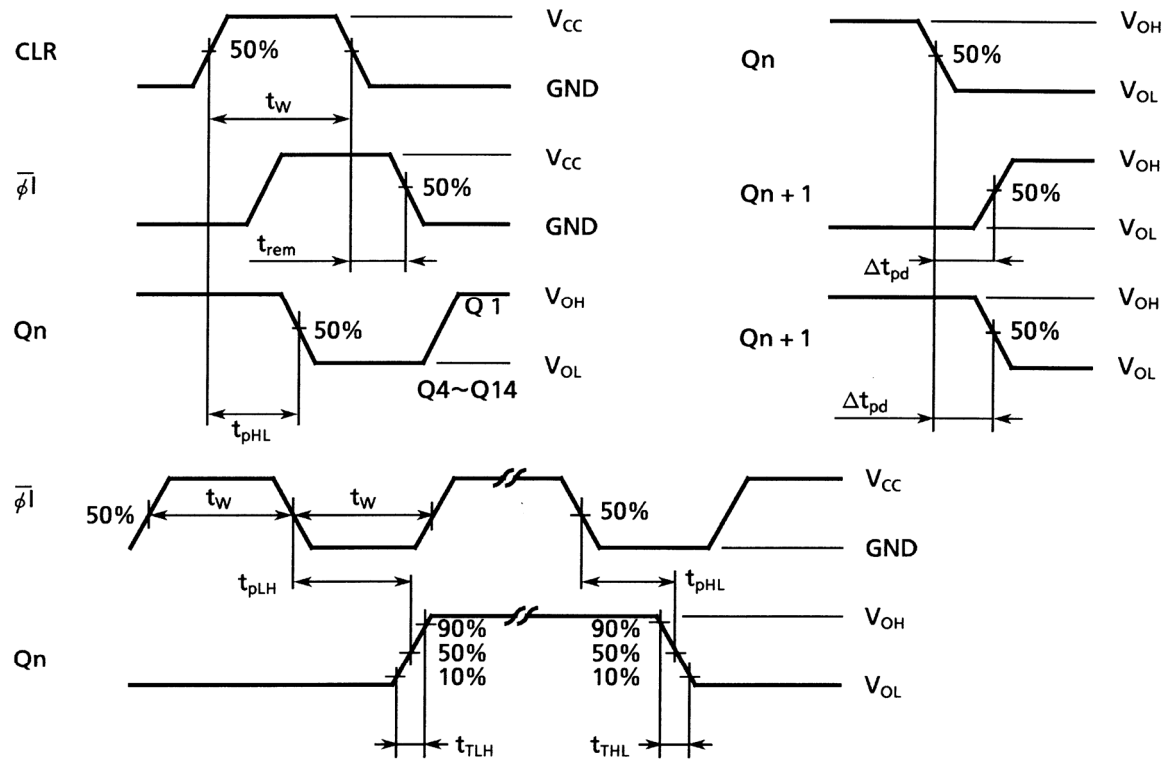
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

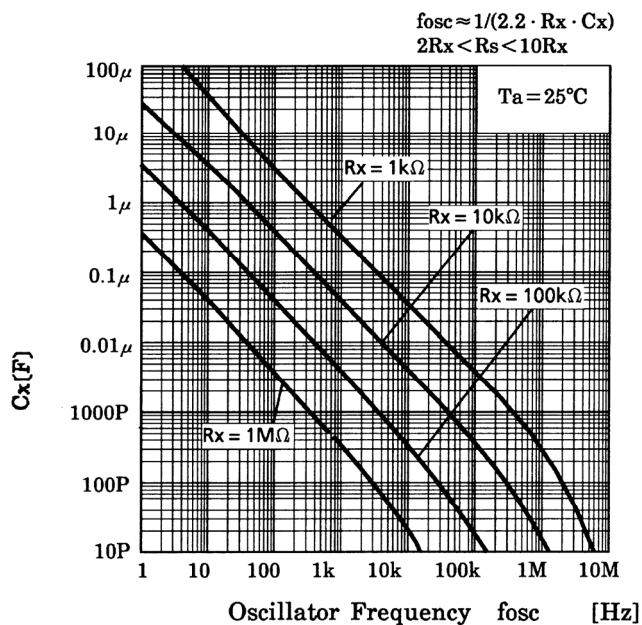
$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

When CR or Crystal oscillation circuit is adopted, the dynamic power dissipation will be greater than the above calculation, because these oscillation circuits spend much supply current.

Switching Characteristics Test Waveform

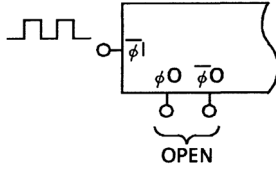


CR Oscillator Characteristics (typical)

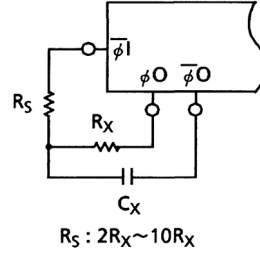


Typical Clock Drive Circuits

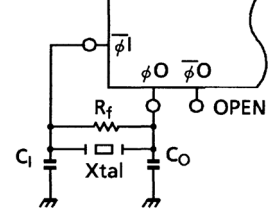
External Clock Drive



Typical RC Circuit



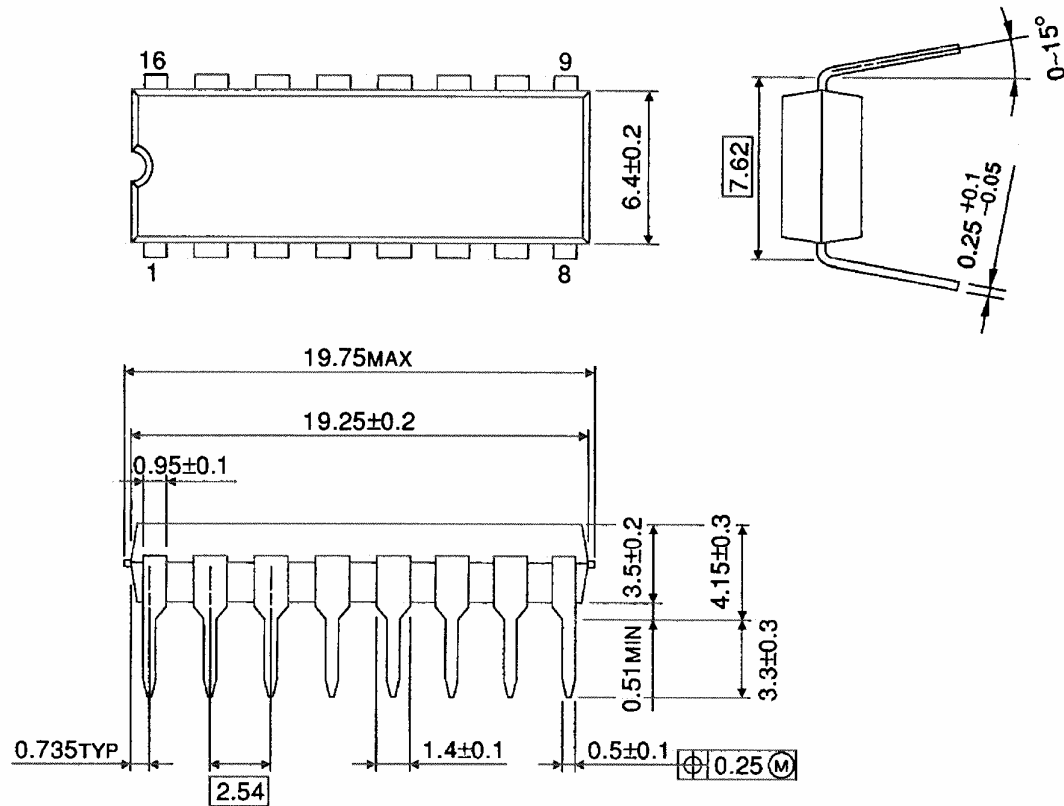
Typical Crystal Circuit



Package Dimensions

DIP16-P-300-2.54A

Unit : mm

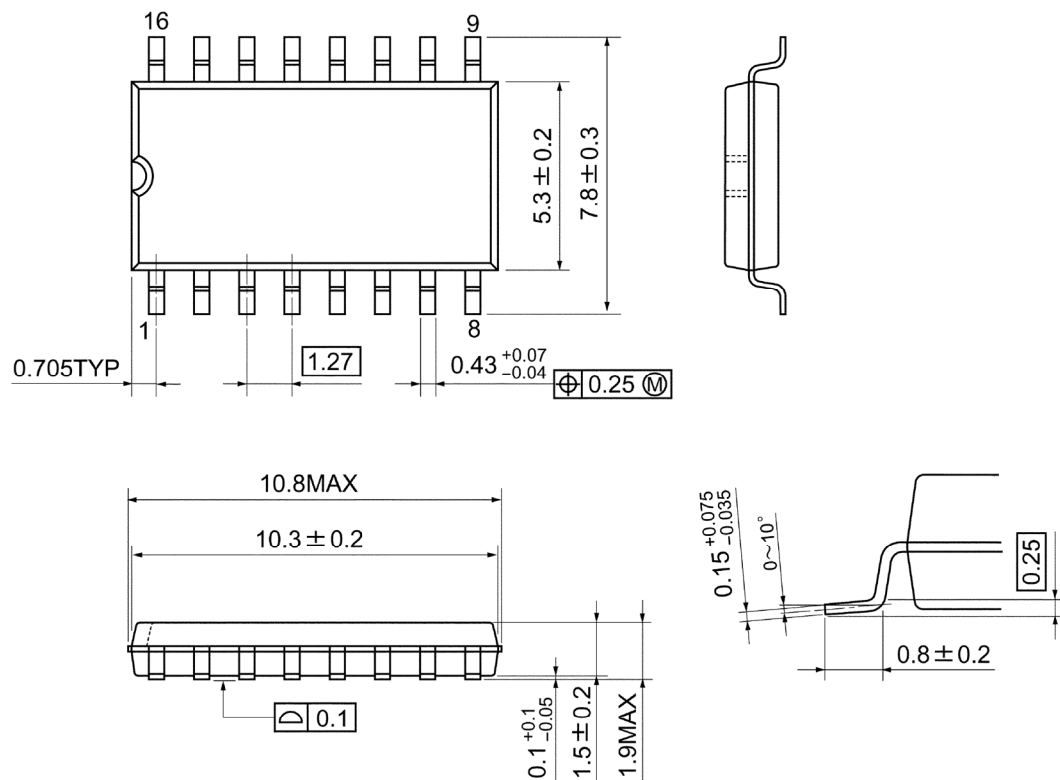


Weight: 1.00 g (typ.)

Package Dimensions

SOP16-P-300-1.27A

Unit: mm

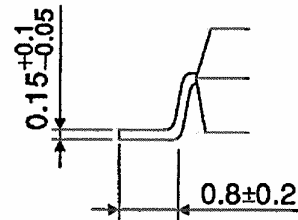
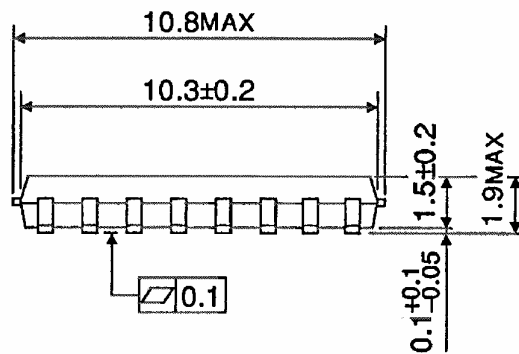
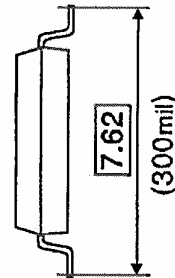


Weight: 0.18 g (typ.)

SOP16-P-300-1.27

Technical drawing of a rectangular component with dimensions and tolerances:

- Overall width: 7.8 ± 0.3
- Overall height: 5.3 ± 0.2
- Top edge features 16 pins, numbered 1 to 16 from left to right.
- Bottom edge features 8 pins, numbered 1 to 8 from left to right.
- Left edge features a semi-circular notch.
- Dimension 0.705 TYP is indicated for the distance from the left edge to the first pin (pin 1).
- Dimension 1.27 is indicated for the distance between adjacent pins.
- Dimension 0.43 ± 0.1 is indicated for the distance from the last pin (pin 8) to the right edge.
- Feature control symbol: $\text{Ø } 0.25 \text{ (M)}$



2006-02-01

Note: Lead (Pb)-Free Packages

DIP16-P-300-2.54A SOP16-P-300-1.27A

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